

SPECIFICATION

• Supplier : Samsung electro-mechanics • Part Number : CL21C331JBANNNC

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 330 pF, 50V, ±5%, C0G, 0805

A. Samsung Part Number

<u>CL</u> <u>21</u> <u>C</u> <u>331</u> <u>J</u> <u>B</u> <u>A</u> <u>N</u> <u>N</u> <u>N</u> <u>O</u> <u>O</u> (1) (2) (3) (4) (5) (6) (7) (8) (9) (9) (1)

1	Series	Samsung Multi-layer Ceramic Capacitor					
2	Size	0805 (inch code)	L: 2.0	± 0.1 mm	W:	1.25 ± 0.1	mm
3	Dielectric	COG	8	Inner electrode		Ni	
4	Capacitance	330 pF		Termination		Cu	
(5)	Capacitance	±5 %		Plating		Sn 100%	(Pb Free)
	tolerance		9	Product		Normal	
6	Rated Voltage	50 V	10	Special		Reserved fo	r future use
7	Thickness	0.65 ± 0.1 mm	11)	Packaging		Cardboard T	ype, 7" reel

B. Samsung Reliablility Test and Judgement condition

	Performance	Test condition				
Capacitance	Within specified tolerance	1Mb±10% 0.5~5Vrms				
Q	1000 min					
Insulation	10,000Mohm or 500Mohm⋅ <i>μ</i> F	Rated Voltage 60~120 sec.				
Resistance	Whichever is Smaller					
Appearance	No abnormal exterior appearance	Microscope (×10)				
Withstanding	No dielectric breakdown or	300% of the rated voltage				
Voltage	mechanical breakdown					
Temperature	COG					
Characterisitcs	(From -55℃ to 125℃, Capacitance change shoud be within ±30PPM/℃)					
Adhesive Strength	No peeling shall be occur on the	500g⋅F, for 10±1 sec.				
of Termination	terminal electrode					
Bending Strength	Capacitance change :	Bending to the limit (1mm)				
	within ±5% or ±0.5pF whichever is larger	with 1.0mm/sec.				
Solderability	More than 95% of terminal surface	1) Sn63Pb37 solder				
	is to be soldered newly	235±5°C, 5±0.5sec.				
		2) SnAg3.0Cu0.5 solder				
		245±5℃, 3±0.3sec.				
		(preheating : 80~120 ℃ for 10~30sec.)				
Resistance to	Capacitance change :	Solder pot : 270±5 ℃, 10±1sec.				
Soldering heat	within ±2.5% or ±0.25pF whichever is larger					
	Tan δ, IR : initial spec.					

	Performance	Test condition			
Vibration Test	Capacitance change :	Amplitude : 1.5mm			
		From 10Hz to 55Hz (return : 1min.)			
	Tan δ, IR : initial spec.	2hours × 3 direction (x, y, z)			
Humidity	Capacitance change :	40±2℃, 90~95%RH, 500+12/-0hrs			
	within ±5% or ±0.5pF whichever is larger				
	Q: 350 min				
	IR: 1000Mohm or 50Mohm · μF				
	Whichever is Smaller				
Moisture	Capacitance change :	With rated voltage			
Resistance	within ±7.5% or ±0.75pF whichever is larger	40±2℃, 90~95%RH, 500+12/-0hrs			
	Q: 200 min				
	IR: 500Mohm or 25Mohm $\cdot \mu$ F				
	Whichever is Smaller				
High Temperature	Capacitance change :	With 200% of the rated voltage			
Resistance	within ±3% or ±0.3pF whichever is larger	Max. operating temperature			
	Q: 350 min	1000+48/-0hrs			
	IR: 1000Mohm or 50Mohm · μF				
	Whichever is Smaller				
Temperature	Capacitance change :	1 cycle condition			
Cycling	within ±2.5% or ±0.25pF whichever is larger	Min. operating temperatu⊢→ 25 °C			
	Tan δ, IR : initial spec.	→ Max. operating temperature → 25°C			
		5 cycle test			

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 250±5 °C, 6sec. Max)

 $^{^{\}star}$ For the more detail Specification, Please refer to the Samsung MLCC catalogue.